

# **60V N-Channel Trench MOSFET**

### **FEATURES**

- Super Low Gate Charge
- 100% EAS Guaranteed
- RoHS compliant
- Green Device Available
- Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Hard switched and high frequency circuits



RoHS

Device Marking and Package Information				
Device	Package	Marking		
CTD06N017	TO-252	CTD06N017		

<b>Absolute Maximum Ratings</b> at $T_j = 25^{\circ}C$ unless otherwise noted				
Parameter		Symbol	Value	Unit
Drain-Source Voltage (V <sub>GS</sub> = 0V)		V <sub>DSS</sub>	60	V
Drain Current-Continuous(Tc=25°C)	(note1)		55	A
Drain Current-Continuous(Tc =100°C)	(note1)	I <sub>D</sub>	35	
Pulsed Drain Current	(note2)	I <sub>DM</sub>	200	А
Gate Source Voltage		V <sub>GSS</sub>	±20	V
Power Dissipation $T_c = 25^{\circ}C$	(note4)	P <sub>D</sub>	100	W
Single Pulse Avalanche Energy	(note3)	E <sub>AS</sub>	64	mJ
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55~+175	٥C

Thermal Characteristics				
Parameter		Symbol	Value	Unit
Thermal Resistance Junction-Case	(note1)	$R_{_{ ext{ ext{ heta}Jc}}}$	1.5	°C/W



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<b>Electrical Characteristics</b> $T_j = 25^{\circ}C$ unless otherwise specified							
Parameter	Cumhal	Test Osnilitions	Value			11	
Farameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			_				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_D = 250\mu A$	60			V	
Zero Gate Voltage Drain Current		$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	uA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 55^{\circ}C$			5	uA	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS}$ = $\pm 20 V$			±100	nA	
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0	1.6	2.5	V	
Drain-Source On-Resistance (note2)	Read	$V_{GS} = 10V, I_{D} = 30A$		12	17	mΩ	
	DS(on)	$R_{DS(on)}$ $V_{GS} = 4.5V, I_D = 20A$		16	25	mΩ	
Dynamic			-				
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V,		2890			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15V,$ f = 1.0MHz		140		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			124			
Total Gate Charge (4.5V)	$Q_g$			50			
Gate-Source Charge	$Q_gs$	$V_{DS} = 30V, I_{D} = 30A, V_{GS} = 10V$		6		nC	
Gate-Drain Charge	$Q_{gd}$			15			
Turn-on Delay Time	t <sub>d(on)</sub>			7.4			
Turn-on Rise Time	t <sub>r</sub>	$V_{DS} = 25V, I_{D} = 30A$ $V_{GS} = 10V, R_{G} = 24\Omega$		5.1		ns	
Turn-off Delay Time	t <sub>d(off)</sub>	$V_{GS} = 100, R_G = 2402$		28.2			
Turn-off Fall Time	t <sub>f</sub>			5.5			
Body Diode Characteristics							
Continuous Body Diode Current	I <sub>s</sub>	T <sub>C</sub> = 25 °C			55	А	
Body Diode Voltage	$V_{SD}$	$T_J = 25^{\circ}C, I_{SD} = 20A, V_{GS} = 0V$			1.2	V	
Reverse Recovery Time	trr	TJ=25℃ IF= 60A,		28		nS	
Reverse Recovery Charge	Qrr	di/dt=100A/µs		40		NC	

#### Notes

1. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.

- 2. The data tested by pulsed , pulse width  $\!\!\! \leq \!\! 300 us$  , duty cycle  $\!\!\! \leq \!\! 2\%$
- 3. The EAS data shows Max. rating . The test condition is VDD =25V,VGS =10V,L=0.1mH
- 4. The power dissipation is limited by 175°C junction temperature

5. The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.



## CTD06N017

### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted





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Figure 11: Normalized Maximum Transient Thermal Impedance (Note F)







Figure B: Resistive Switching Test Circuit and Waveform



Figure C: Unclamped Inductive Switching Test Circuit and Waveform





TO-252



Unit: mm				
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.20		
A2	0.97	1.17		
b	0.68	0.90		
b3	5.20	5.50		
с	0.43	0.63		
D	5.98	6. 22		
D1	5. 30REF			
E	6.40	6.80		
E1	4.63	-		

Unit: mm				
Symbol	Min.	Max.		
е	2. 286BSC			
Н	9.40	10.50		
L	1.38	1.75		
L1	2.90REF			
L2	0. 51BSC			
L3	0.88	1.28		
L4	_	1.00		
L5	1.65	1.95		
θ	0°	8°		



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